TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LVX138F,TC74LVX138FN,TC74LVX138FT

3-to-8 Line Decoder

The TC74LVX138F/ FN/ FT is a high-speed CMOS 3-to-8 line decoder fabricated with silicon gate CMOS technology. Designed for use in 3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

This device is suitable for low-voltage and battery operated systems.

When the device is enabled, 3 Binary Select inputs (A, B and C) determine which one of the outputs ($\overline{Y}0 \cdot \overline{Y}7$) will go low. When enable input G1 is held low or either $\overline{G}2A$ or $\overline{G}2B$ is held high, decoding function is inhibited and all outputs go high.

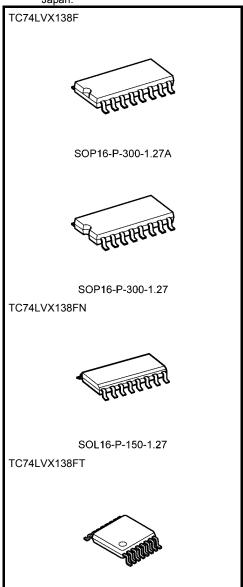
G1, $\overline{G}2A$, and $\overline{G}2B$ inputs are provided to ease cascade connection and for use as an address decoder for memory systems.

An input protection circuit ensures that 0 to 5.5V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

- High-speed: $t_{pd} = 5.5 \text{ ns (typ.) (VCC} = 3.3 \text{ V)}$
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max) (Ta} = 25 ^{\circ}\text{C)}$
- Input voltage level: $V_{IL} = 0.8 \text{ V (max) (V}_{CC} = 3 \text{ V)}$
 - $V_{IH} = 2.0 \text{ V (min) (V}_{CC} = 3 \text{ V)}$
- Power-down protection provided on all inputs
- $\bullet \quad Balanced\ propagation\ delays\hbox{:}\ t_{pLH} \simeq t_{pHL}$
- Pin and function compatible with 74HC138

Note: xxxFN (JEDEC SOP) is not available in



Weight

 SOP16-P-300-1.27A
 : 0.18 g (typ.)

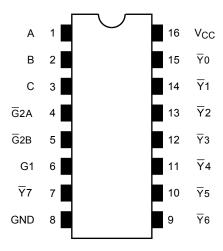
 SOP16-P-300-1.27
 : 0.18 g (typ.)

 SOL16-P-150-1.27
 : 0.12 g (typ.)

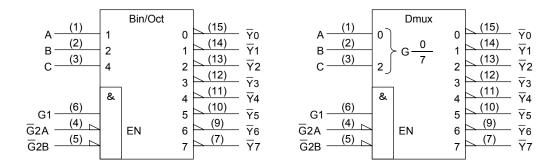
 TSSOP16-P-0044-0.65A
 : 0.06 g (typ.)

TSSOP16-P-0044-0.65A

Pin Assignment (top view)



IEC Logic Symbol



Truth Table

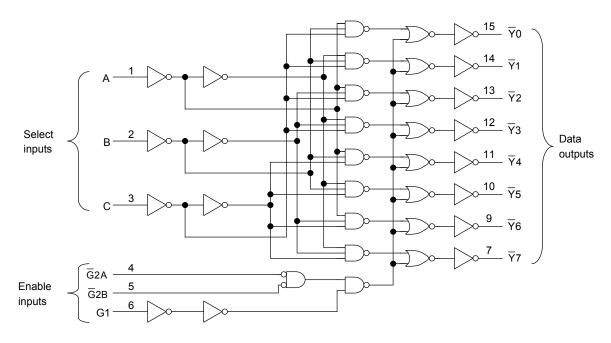
	Inputs						Outputs								
Enable		Select			₹0	<u>7</u> 1	_ Y2	_ Y3	<u>-</u> Y4	<u>7</u> 5	Y5 Y6	<u>7</u> 7	Selected Output		
G1	G ₂ A	G ₂ B	С	В	Α	10	11	12	13	14	13	10	1 /		
L	Х	Х	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н	None	
Х	Н	X	X	Х	Х	Η	Η	Н	Н	Η	Н	Η	Н	None	
Х	Х	Η	X	Х	Х	Η	Η	Н	Н	Η	Н	Η	Н	None	
Н	L	L	L	L	L	L	Н	Н	Н	Н	Н	Н	Н	₹0	
Н	L	L	L	L	Н	Н	L	Н	Н	Н	Н	Н	Н	₹1	
Н	L	L	L	Н	L	Н	Н	L	Н	Н	Н	Н	Н	Ÿ2	
Н	L	L	L	Н	Н	Н	Н	Н	L	Н	Н	Н	Н	Y 3	
Н	L	L	Н	L	L	Н	Н	Н	Н	L	Н	Н	Н	Y 4	
Н	L	L	Н	L	Н	Н	Н	Н	Н	Н	L	Н	Н	Ȳ5	
Н	L	L	Н	Н	L	Н	Н	Н	Н	Н	Н	L	Н	₹6	
Н	L	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	L	Ÿ7	

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X: Don't care



System Diagram



Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit	
Supply voltage range	V _{CC}	-0.5 to 7.0	V	
DC input voltage	V _{IN}	-0.5 to 7.0	V	
DC output voltage	V _{OUT}	-0.5 to V_{CC} + 0.5	٧	
Input diode current	I _{IK}	-20	mA	
Output diode current	I _{OK}	±20	mA	
DC output current	lout	±25	mA	
DC V _{CC} /ground current	I _{CC}	±75	mA	
Power dissipation	P_{D}	180	mW	
Storage temperature	T _{stg}	-65 to 150	°C	

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2.0 to 3.6	V
Input voltage	V _{IN}	0 to 5.5	V
Output voltage	V _{OUT}	0 to V _{CC}	V
Operating temperature	T _{opr}	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 100	ns/V

Note: The recommended operating conditions are required to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.

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Electrical Characteristics

DC Characteristics

Characte	Symbol Test Condition			Ta = 25°C			Ta = -40 to 85°C		Unit		
					V _{CC} (V)	Min	Тур.	Max	Min	Max	
Input voltage					2.0	1.5	_	_	1.5	_	
	H-level	V _{IH}	_		3.0	2.0	_	_	2.0	_	V
					3.6	2.4	_	_	2.4	_	
input voltage					2.0	_	_	0.5	_	0.5	
	L-level	V_{IL}		_	3.0	_	_	0.8	_	0.8	
					3.6	_	_	0.8	_	0.8	
			V _{IN} = V _{IH} or V _{IL}	$I_{OH} = -50 \mu A$	2.0	1.9	2.0	_	1.9	_	
	H-level	V_{OH}		I _{OH} = -50 μA	3.0	2.9	3.0	_	2.9	_	
Output valtage				I _{OH} = -4 mA	3.0	2.58	_	_	2.48	_	V
Output voltage			V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	2.0	_	0	0.1	_	0.1	V
	L-level	V_{OL}		I _{OL} = 50 μA	3.0	_	0	0.1	_	0.1	
			"	I _{OL} = 4 mA	3.0	_	_	0.36	_	0.44	
Input leakage cur	I _{IN}	V _{IN} = 5.5 V or GND		3.6	_	_	±0.1	_	±1.0	μА	
Quiescent supply	current	Icc	V _{IN} = V _{CC} or GND		3.6		_	4.0	_	40.0	μА



AC Characteristics (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition			-	Ta = 25°0		Ta = -40 to 85°C		Unit
			V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	
	t		2.7	15	_	7.1	13.8	1.0	16.5	ns
Propagation delay time	t _{pLH}			50	_	9.6	17.3	1.0	20.0	
$(A, B, C-\overline{Y})$	+		3.3 ± 0.3	15	_	5.5	8.8	1.0	10.5	113
	t _{pHL}		3.3 ± 0.3	50	_	8.0	12.3	1.0	14.0	
	+		2.7	15	_	8.7	16.3	1.0	19.5	ns
Propagation delay time	t _{pLH}			50	_	11.2	19.8	1.0	23.0	
(G1- \overline{Y})	t _{pHL}	_	3.3 ± 0.3	15	_	6.8	10.6	1.0	12.5	115
			3.3 ± 0.3	50	_	9.3	14.1	1.0	16.0	
	t _{pLH}		2.7 3.3 ± 0.3	15	_	8.8	16.0	1.0	18.5	- ns
Propagation delay time				50	_	11.3	19.5	1.0	22.0	
(G 2 - Y)	+	_		15	_	6.9	10.4	1.0	11.5	
	t _{pHL}			50	_	9.4	13.9	1.0	15.0	
Output to output skew	t _{osLH}	(Note 1)	2.7	50	_	_	2.5	_	2.5	ns
Output to output skew	t _{osHL}	(Note 1)	3.3 ± 0.3	50	_	_	2.5	_	2.5	115
Input capacitance	C _{IN}			(Note 2)	_	4	10	_	10	pF
Power dissipation capacitance	C _{PD}			(Note 3)		34	_	_		pF

Note 1: Parameter guaranteed by design.

 $(t_{\text{OSLH}} = |t_{\text{pLHm}} - t_{\text{pLHn}}|, \ t_{\text{OSHL}} = |t_{\text{pHLm}} - t_{\text{pHLn}}|)$

Note 2: Parameter guaranteed by design.

Note 3: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation:

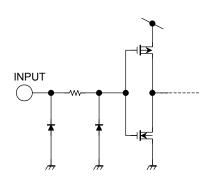
 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

Noise Characteristics (Ta = 25°C, input: $t_r = t_f = 3 \text{ ns}$, $C_L = 50 \text{ pF}$)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Limit	Unit
Quiet output maximum dynamic V _{OL}	V _{OLP}	_	3.3	_	0.5	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	_	3.3	_	-0.5	V
Minimum high level dynamic input voltage $V_{\mbox{\scriptsize IH}}$	V _{IHD}	_	3.3	_	2.0	V
Maximum low level dynamic input voltage V_{IL}	V _{ILD}	_	3.3		0.8	V

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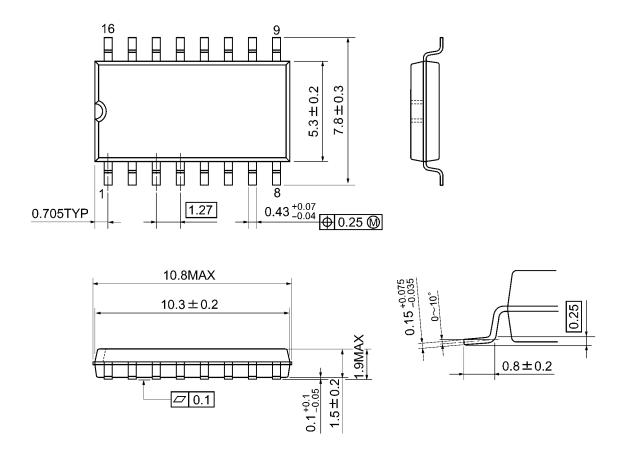
Input Equivalent Circuit



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Package Dimensions

SOP16-P-300-1.27A Unit: mm



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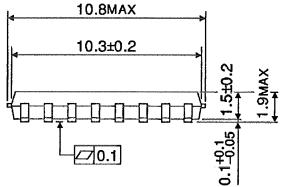
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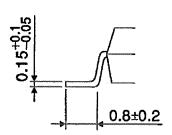
Package Dimensions

SOP16-P-300-1.27

Unit: mm

16
9
9
9
9
10.705TYP
10.8MAX

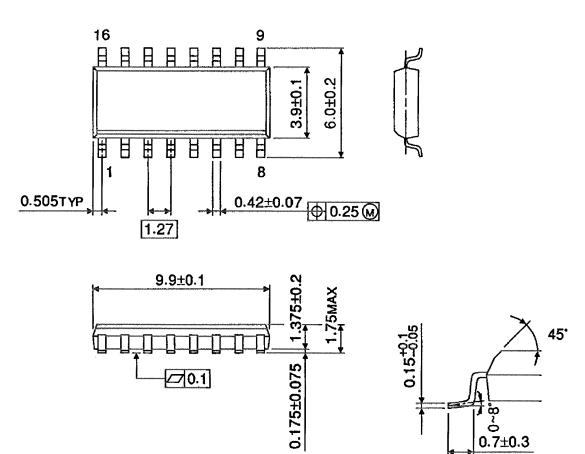




Weight: 0.18 g (typ.)

Package Dimensions (Note)

SOL16-P-150-1.27 Unit: mm



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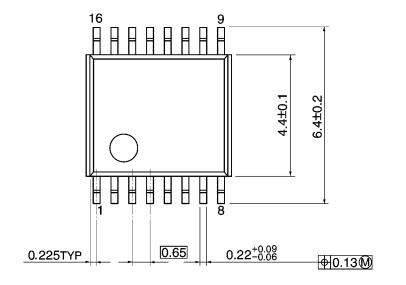
Note: This package is not available in Japan.

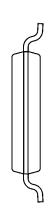
Weight: 0.12 g (typ.)

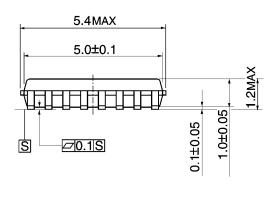
Package Dimensions

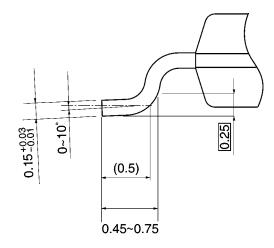
TSSOP16-P-0044-0.65A

Unit: mm









Weight: 0.06 g (typ.)

Note: Lead (Pb)-Free Packages

SOP16-P-300-1.27A SOL16-P-150-1.27 TSSOP16-P-0044-0.65A

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